

# COMSOL模拟在扫描电化学显微镜 (SECM) 中的应用

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# 提纲

1. 超微电极和SECM简介
2. COMSOL建模的关键
3. 3个具体模拟案例
4. 展望

# 1. 超微电极与SECM



# 超微电极

◆ 扩散层  $(2Dt)^{0.5}$

◆ 微米级

$5 < \text{tip diameter} < 100 \mu\text{m}$

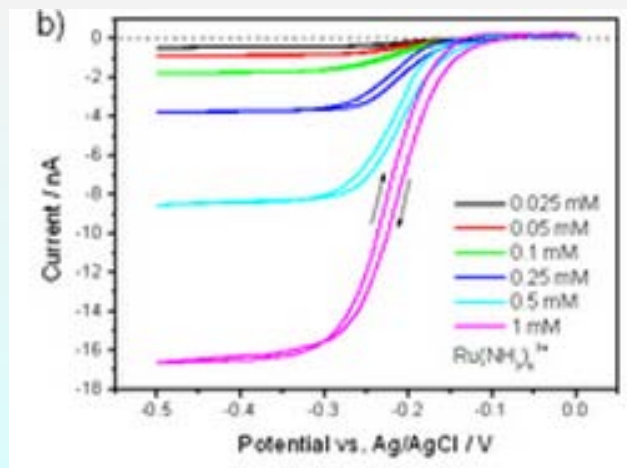
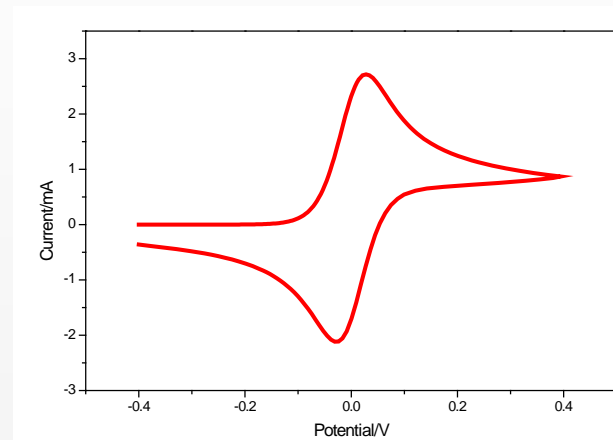
◆ 次微米和纳米电极

$< 1 \mu\text{m}$  or  $< 100 \text{nm}$ , (0.6 nm)

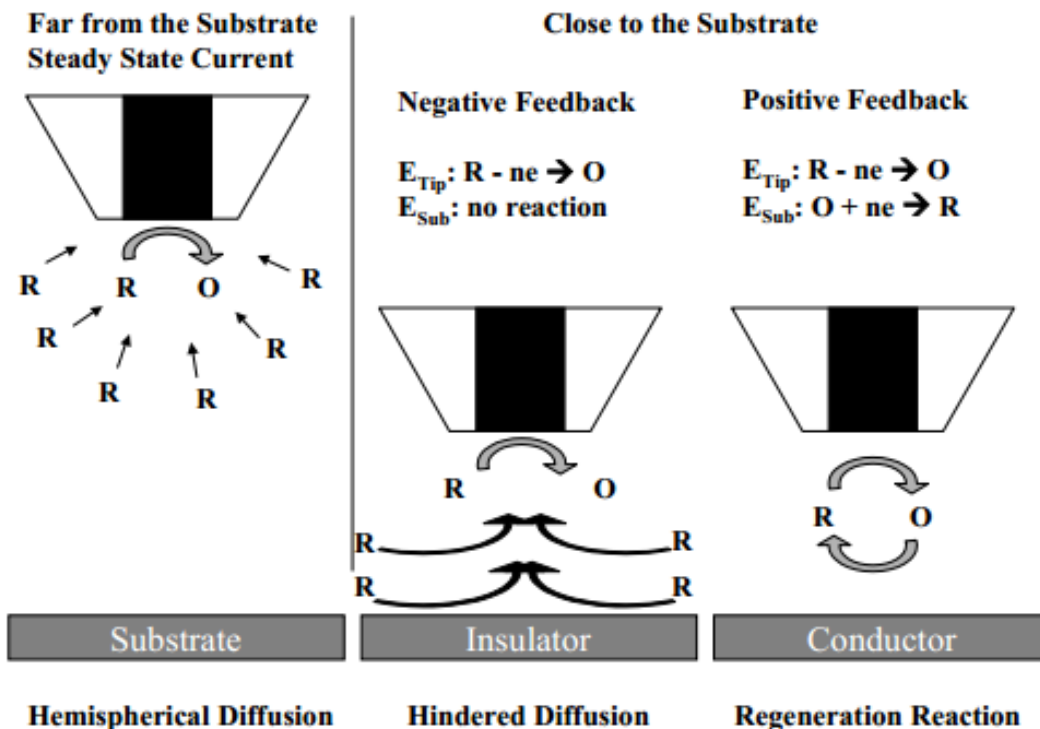
iR降小，时间常数 ( $\tau$ ) 小

稳态

核心：非线性扩散



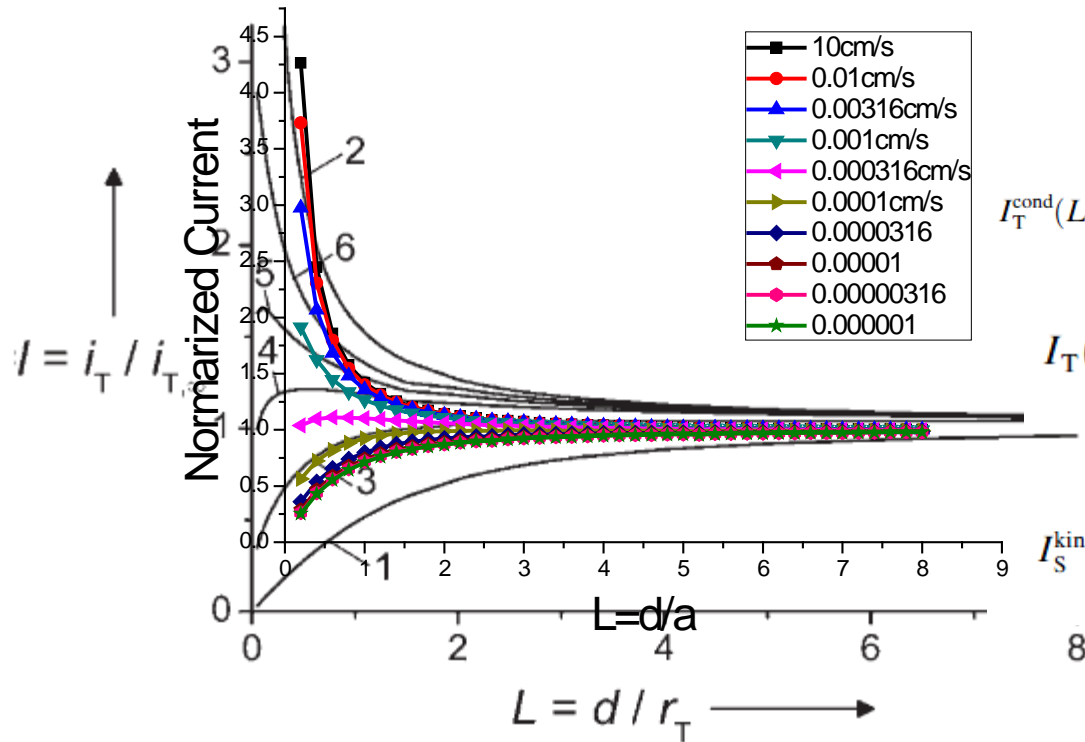
# SECM基础



距离  
基底电极性质

Basic principles of SECM. (a) With UME far from substrate, diffusion leads to a steady-state current  $i_{T\infty}$  (b) UME near an insulating substrate. Hindered diffusion leads to  $i_T < i_{T\infty}$  (c) UME near a conductive substrate. Positive feedback leads to  $i_T > i_{T\infty}$ .

# 基底电极动力学k的影响



$$I_T^{\text{ins}}(L) = \frac{i_T}{i_{T,\infty}} = \frac{1}{0.40472 + \frac{1.60185}{L} + 0.58819 \exp\left(\frac{-2.37294}{L}\right)}$$

$$I_T^{\text{cond}}(L) = \frac{i_T}{i_{T,\infty}} = 0.72627 + \frac{0.76651}{L} + 0.26015 \exp\left(\frac{-1.41332}{L}\right)$$

$$I_T(L) = \frac{i_T}{i_{T,\infty}} = I_T^{\text{ins}}(L) + I_S^{\text{kin}}(L) \left(1 - \frac{I_T^{\text{ins}}(L)}{I_T^{\text{cond}}(L)}\right)$$

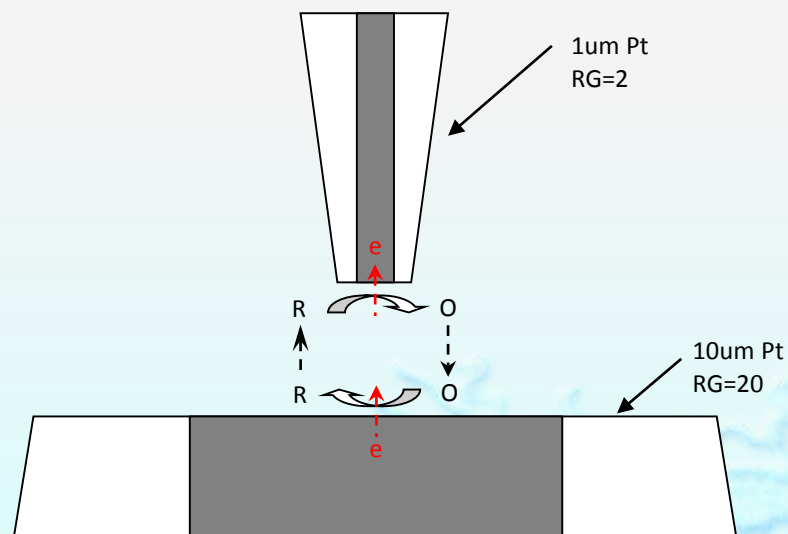
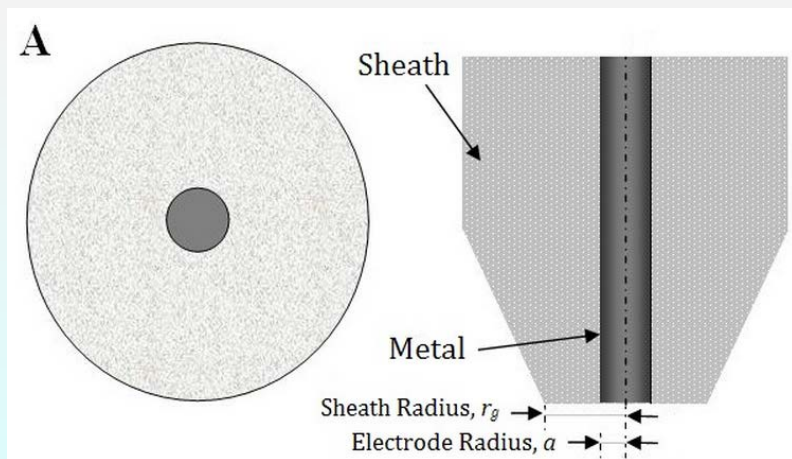
$$I_S^{\text{kin}}(L, k_{\text{eff}}) = \frac{0.78377}{L(1 + \frac{1}{\kappa L})} + \frac{0.68 + 0.3315 \exp\left(\frac{-1.0672}{L}\right)}{1 + \frac{(11/\kappa L) + 7.3}{110 - 40L}}$$

Calculated current-distance curves of a UME (RG=10) for hindered diffusion (Eq. 1, curve 1), diffusion-controlled recycling of the mediator (Eq. 2, curve 2), and kinetically limited mediator recycling (Eqs. 2 and 4) with  $k = k_{\text{eff}} r_T / D = 0.3$  (3), 1.0 (4), 1.8 (5), 3.6 (6).

# 扫描电化学显微镜系统关键参数

- ◆ 电极半径,  $\alpha$
- ◆ 玻璃与电极半径比,  $R_g$
- ◆ 探针与基底距离,  $d$ ,  $L=d/\alpha$

分辨率



## 2. 电化学模拟的核心基础

◆ Nernst-Planck equation for one dimension

$$◆ J_i(x) = -D_i \frac{\partial C_i(x)}{\partial x} - \frac{Z_i F}{RT} D_i C_i \frac{\partial \phi(x)}{\partial x} + C_i v(x)$$

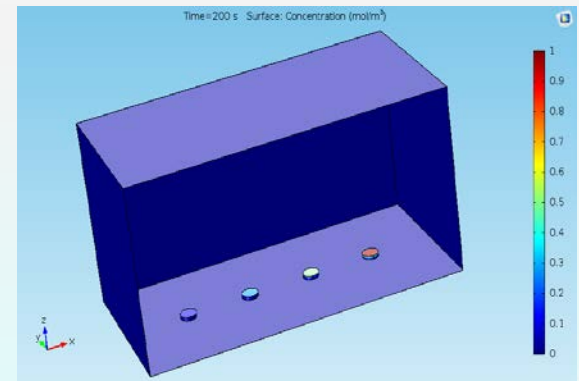
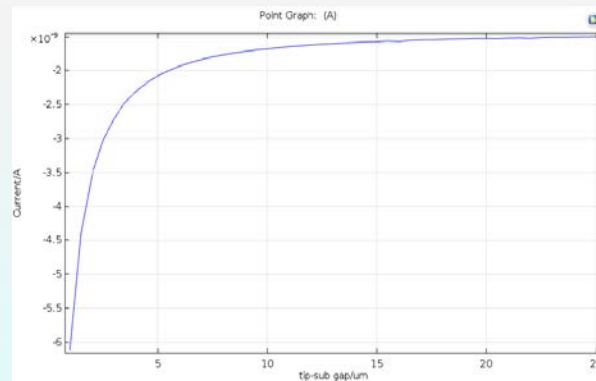
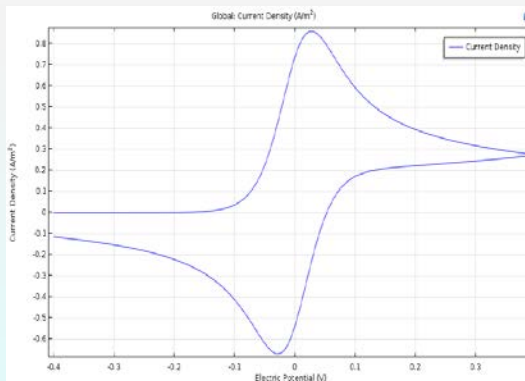
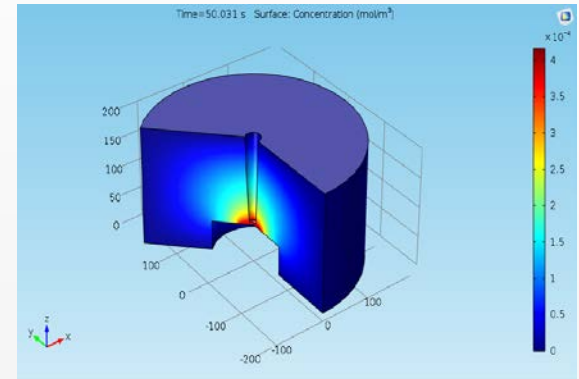
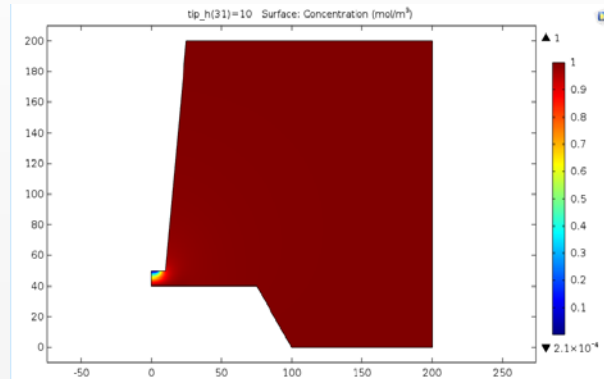
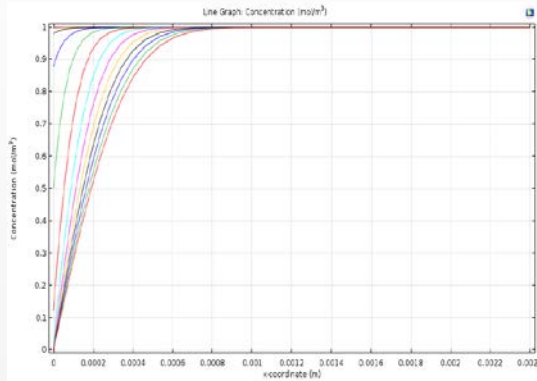
$$◆ \text{Fick's first law: } J_i(x, t) = -D_i \frac{\partial C_i(x, t)}{\partial x}$$

$$◆ \text{Fick's second law: } \frac{\partial C_i(x, t)}{\partial t} = D_i \frac{\partial^2 C_i(x, t)}{\partial x^2}$$

$$◆ \text{Electron transfer: } i = F A k^0 [c_O(0, t) e^{-af(E-E^0')} - c_R(0, t) e^{(1-a)f(E-E^0')}]$$



# COMSOL 建模

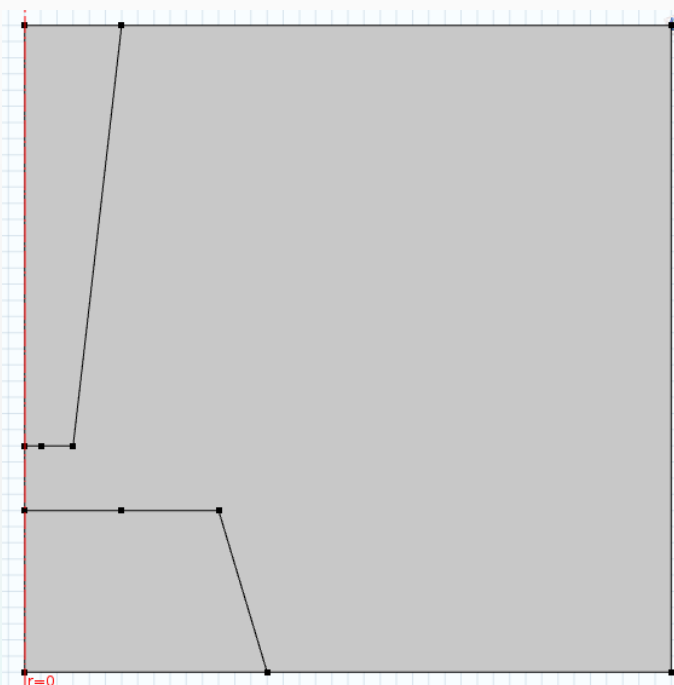
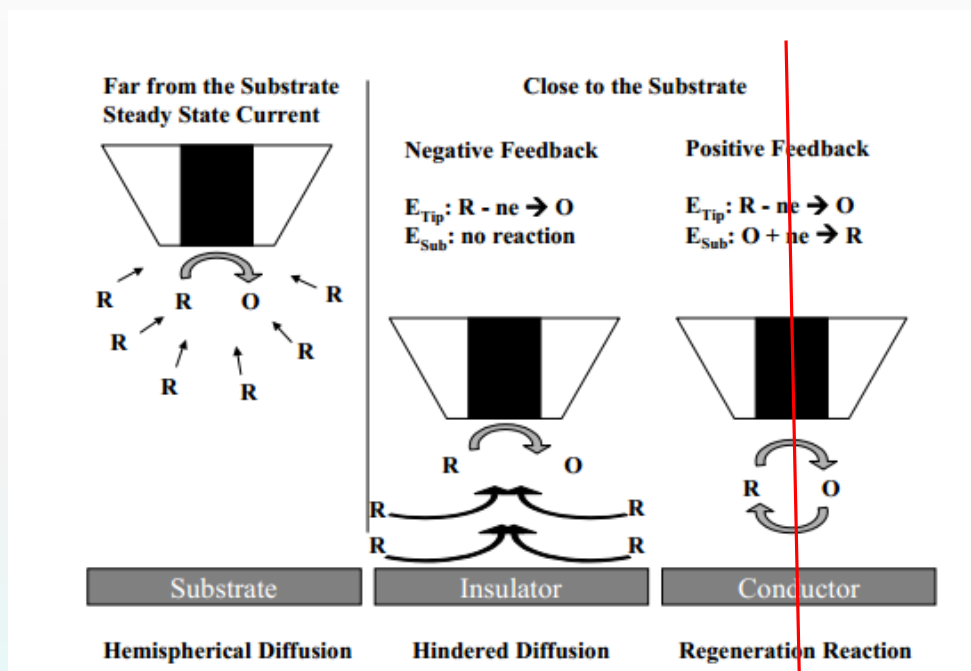


(a) one-dimensional linear diffusion concentration distribution, (b) one-dimensional cyclic voltammetry curve, (c) two-dimensional concentration distribution of SECM, (d) pure positive feedback approach curve of SECM, (e) three dimensional distribution of SECM, (f) concentration distribution under different defect.

# 实例1: 距离确定



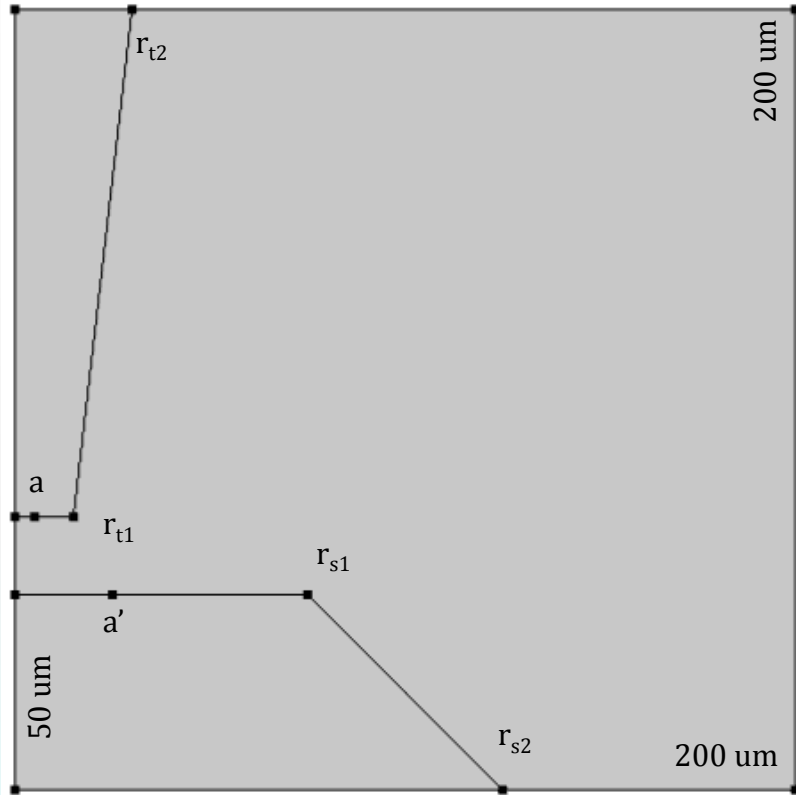
# 存在的问题及解决方案



三维球形扩散  
没有准确的计算解

二维轴对称模型  
数值解

# 数学模型



Reaction:  $O + e \leftrightarrow R$

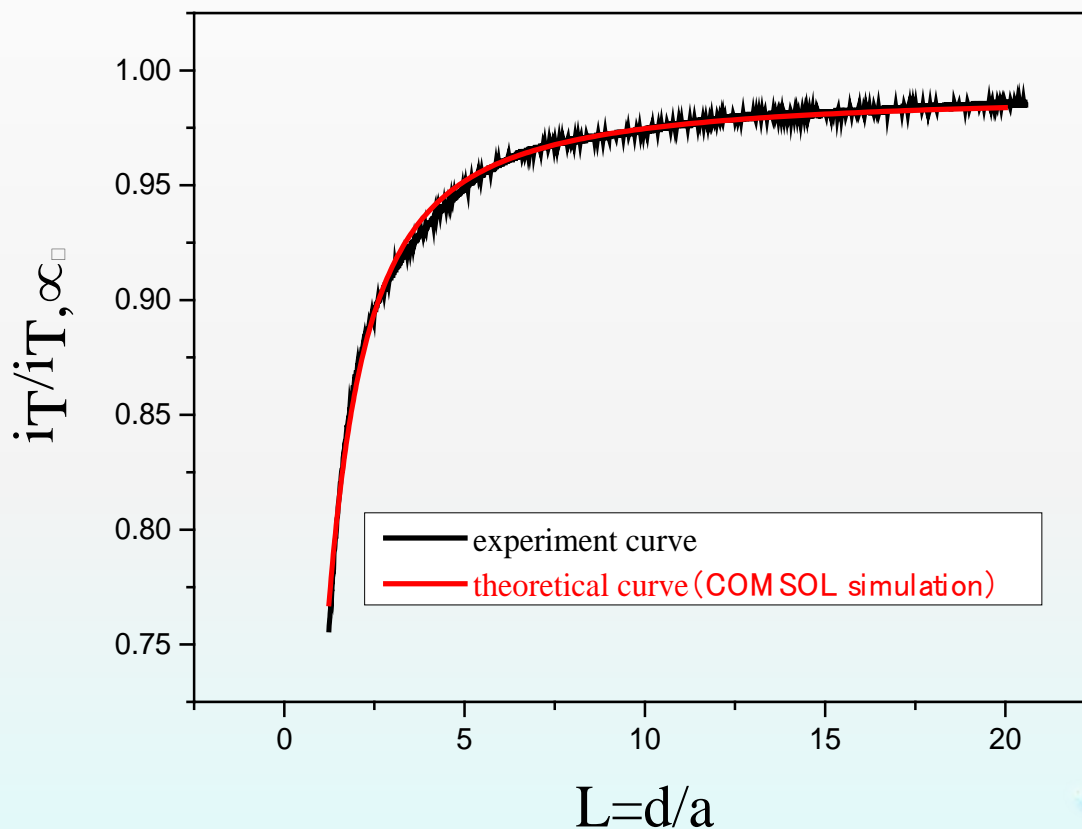
Initial condition:  $C_O = 0, C_R = C_R^*$

N o.	z coordinate	r coordinate	Boundary conditions
1	50 μm + d	0 ≤ r ≤ a	$C_R = 0$ $D_R \frac{\partial C_R}{\partial z} = -D_O \frac{\partial C_O}{\partial z}$
2	50 μm + d	a ≤ r ≤ r <sub>t1</sub>	$D_O \frac{\partial C_O}{\partial z} = D_R \frac{\partial C_R}{\partial z} = 0$
3	$\frac{150 - d}{r_{t2} - r_{t1}} * r$ $+ \frac{(50 + d) * r_{t2} - 200 * r_{t1}}{r_{t2} - r_{t1}}$	r <sub>t1</sub> ≤ r ≤ r <sub>t2</sub>	$D_O \frac{\partial C_O}{\partial z} = D_R \frac{\partial C_R}{\partial z} = 0$
4	200 μm	r <sub>t2</sub> ≤ r ≤ 200 μm	$C_O = 0, C_R = C_R^*$
5	50 μm	0 ≤ r ≤ a'	$C_O = 0$ $D_O \frac{\partial C_O}{\partial z} = -D_R \frac{\partial C_R}{\partial z}$
6	50 μm	a' ≤ r ≤ r <sub>s1</sub>	$D_O \frac{\partial C_O}{\partial z} = D_R \frac{\partial C_R}{\partial z} = 0$
7	$\frac{-50}{r_{s2} - r_{s1}} * r + \frac{50 * r_{s2}}{r_{s2} - r_{s1}}$	r <sub>s1</sub> ≤ r ≤ r <sub>s2</sub>	$D_O \frac{\partial C_O}{\partial z} = D_R \frac{\partial C_R}{\partial z} = 0$
8	0 μm	r <sub>s2</sub> ≤ r ≤ 200 μm	$C_O = 0, C_R = C_R^*$
9	0 ≤ z ≤ 200 μm	r = 200 μm	$C_O = 0, C_R = C_R^*$
10	50 μm ≤ z ≤ 50 μm + d	r = 0	$D_O \frac{\partial C_O}{\partial z} = D_R \frac{\partial C_R}{\partial z} = 0$

$$\frac{\partial C_O}{\partial t} = D_O \left[ \frac{\partial^2 C_O}{\partial r^2} + \frac{1}{r} \frac{\partial C_O}{\partial r} + \frac{\partial^2 C_O}{\partial z^2} \right]$$

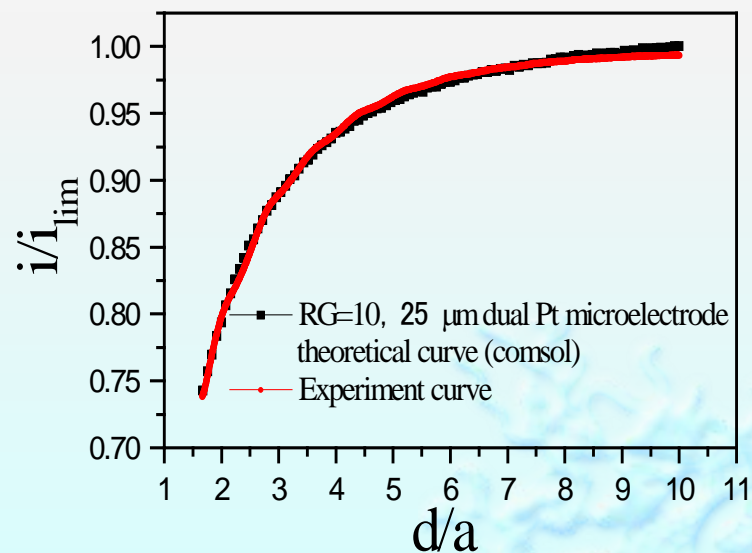
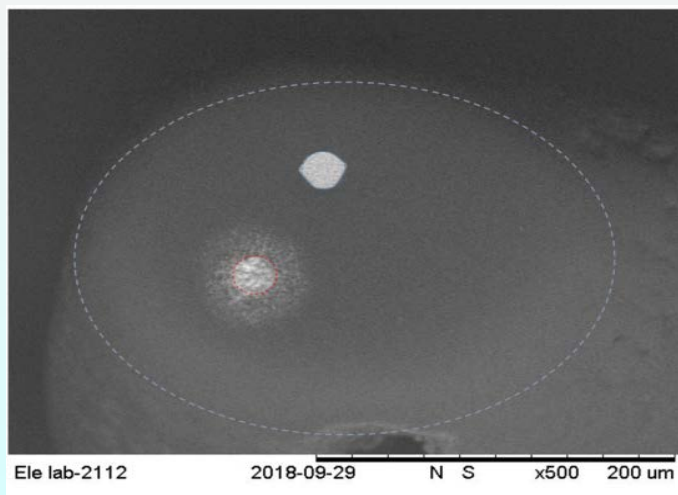
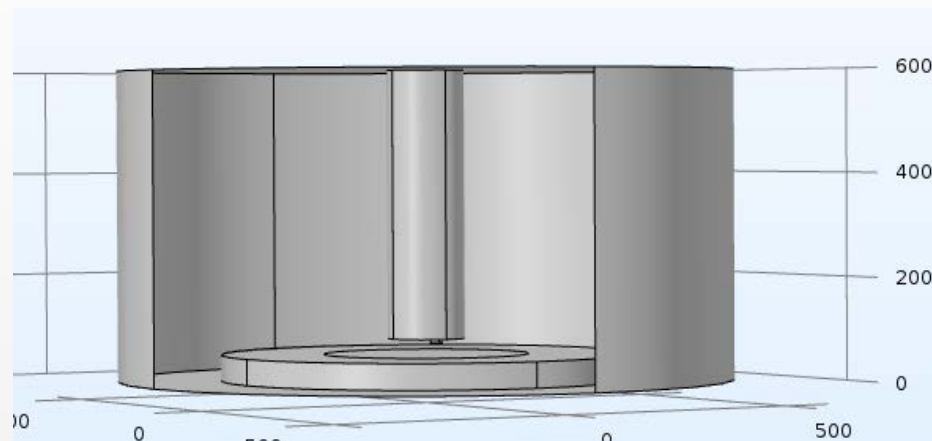
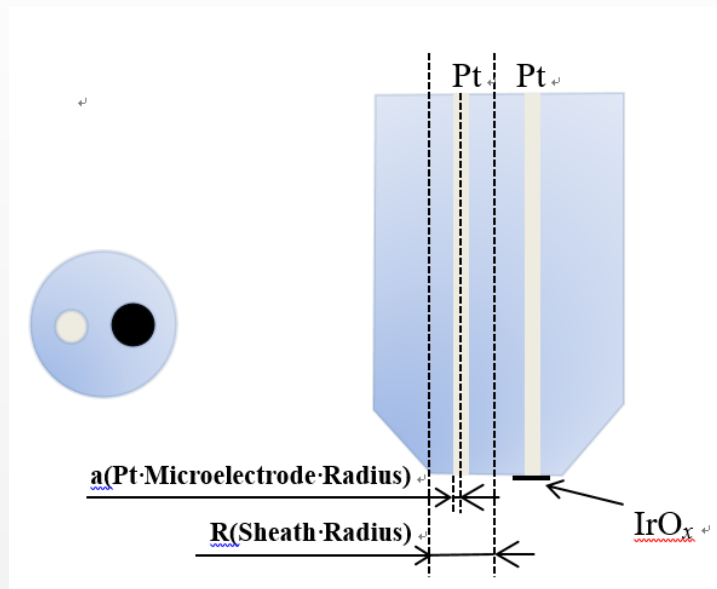
$$\frac{\partial C_R}{\partial t} = D_R \left[ \frac{\partial^2 C_R}{\partial r^2} + \frac{1}{r} \frac{\partial C_R}{\partial r} + \frac{\partial^2 C_R}{\partial z^2} \right]$$

# 距离确定



逼近曲线，从SECM扫描响应的电流即可获得准确的距离。

# 非对称实例-3维模型



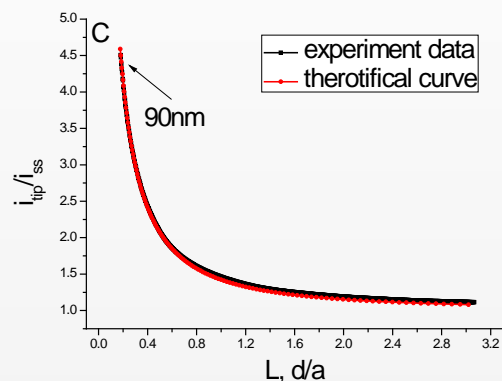
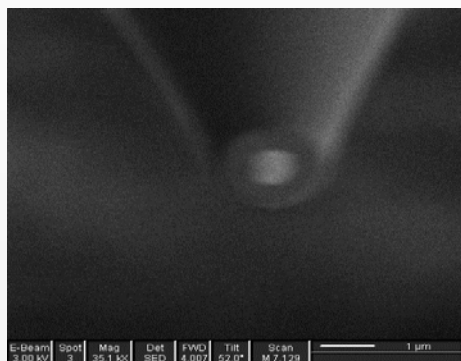
Z.J. Zhu, Z.N. Ye, Q.H. Zhang, J.Q. Zhang, F.H. Cao\*, **Electrochemistry Communications**, 88 (2018) 47.

Z.J. Zhu, X.Y. Liu, Z.N. Ye, J.Q. Zhang, F.H. Cao\*, J.X. Zhang,, **Sensors and Actuators B: Chemical**, 255 (2018) 1974.

# 实例2：空间分辨率



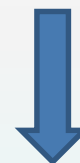
# 存在的问题？



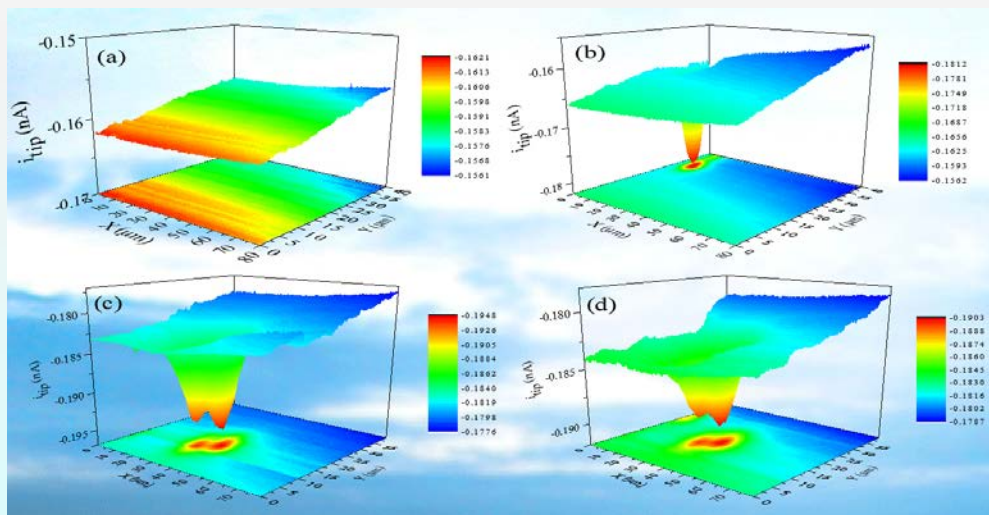
微观不均匀性



- ① 次微米超微电极
- ② 扫描电化学显微镜
- ③ 实验+模拟方法

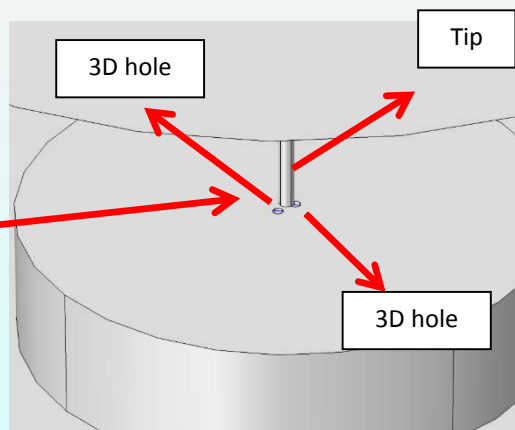
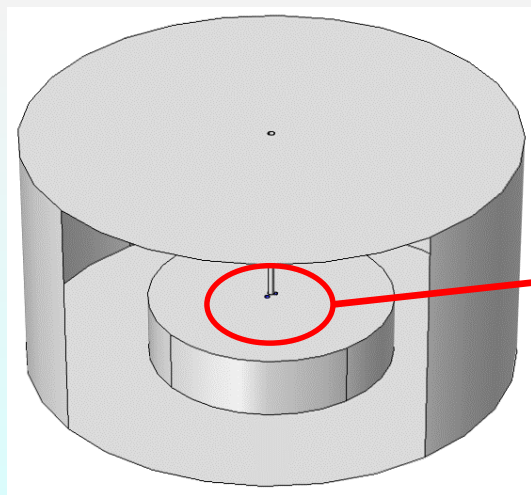
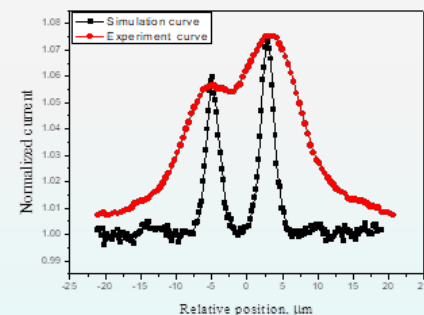
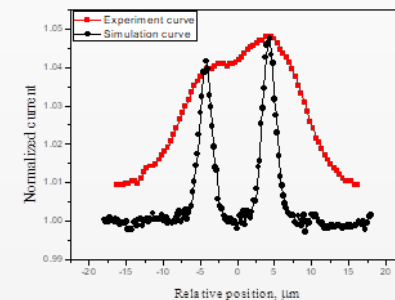
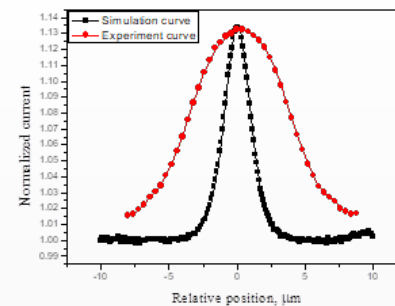
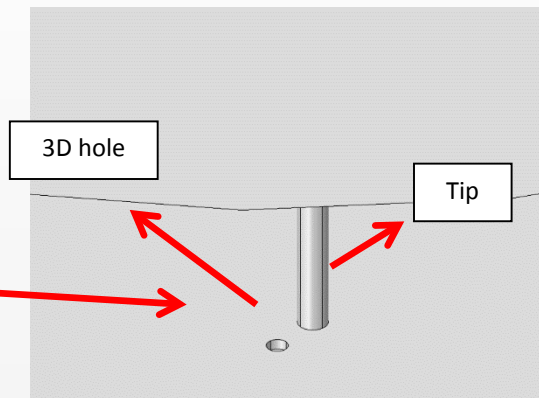
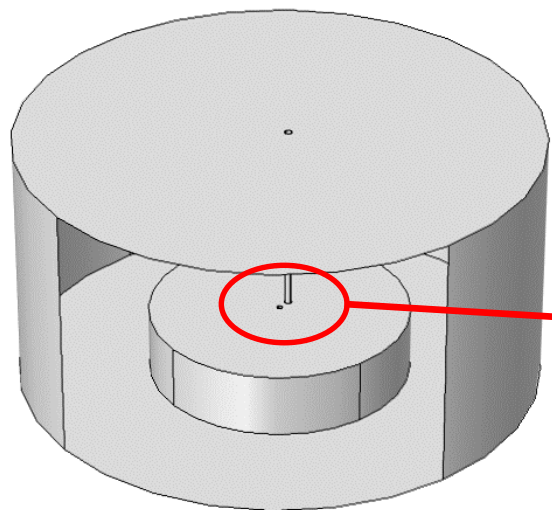


第一次报道扫描电化学显微镜原位观察局部腐蚀，并量化空间分辨率





# 模拟分析结果



单孔半径和深度：0.5和0.42  
微米；相邻孔：孔径介于  
0.36~0.45 微米，深度介于  
0.87~0.92 微米

Z.N. Ye, Q.H. Zhang, X.Y. Liu, J.Q. Zhang, F.H. Cao\*, *Corrosion Science*, 143 (2018) 221

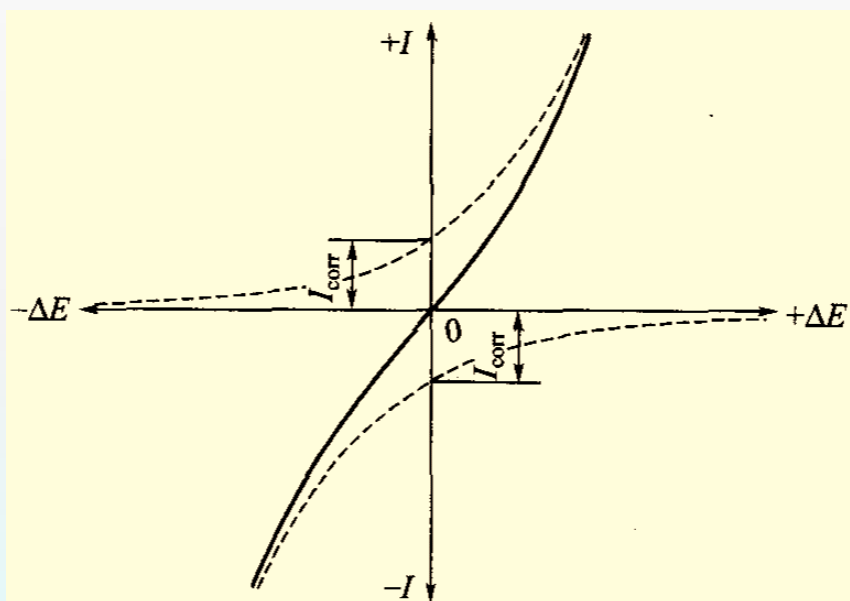
F.H. Cao, J. Kim, A.J. Bard\*, *Journal of the American Chemical Society*, 136 (2014) 18163

# 实例3：动力学分析



# 存在的问题？

腐蚀多反应非平衡特征  
表观电流定量分析与反应动力学  
学研究缺乏

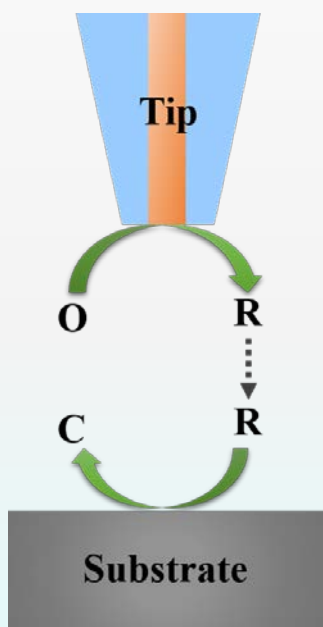


- ① 活性探针产生-基底收集模式  
② COMSOL多物理场模拟分析

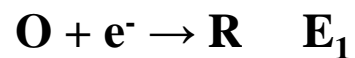
第一次实现腐蚀电极表观电流定量  
分离及其阴阳极反应动力学报道

# 反应模型

传统产生/收集模式



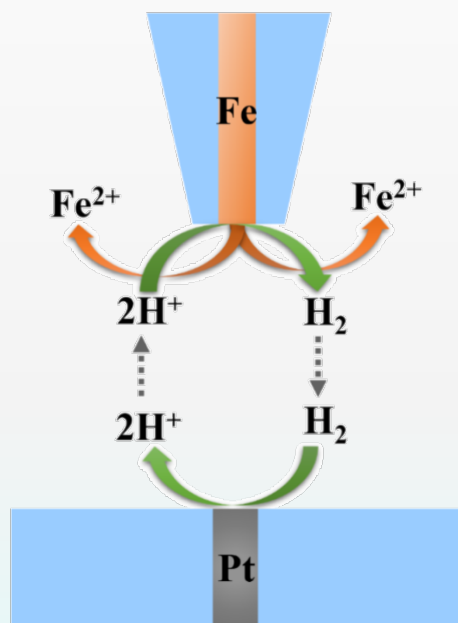
Single reaction on Tip:



Reaction on Substrate:



改进产生/收集模式 (除氧)



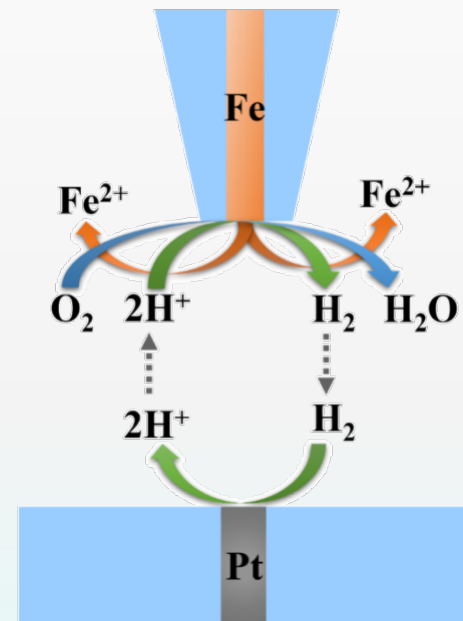
Two reactions on Tip:



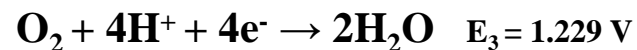
Reactions on Substrate:



改进产生/收集模式 (自然)



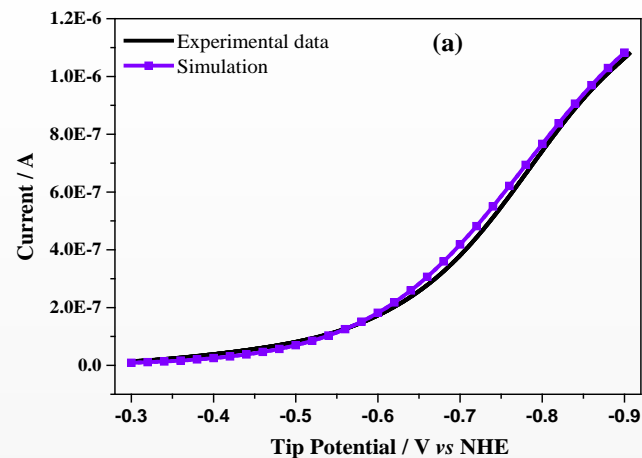
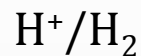
Three reactions on Tip:



Reactions on Substrate:



# 结果

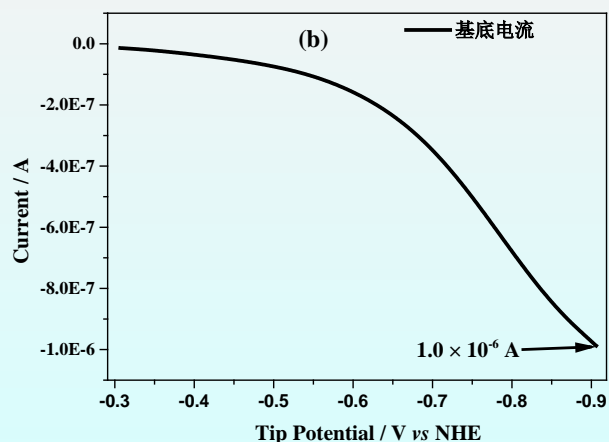
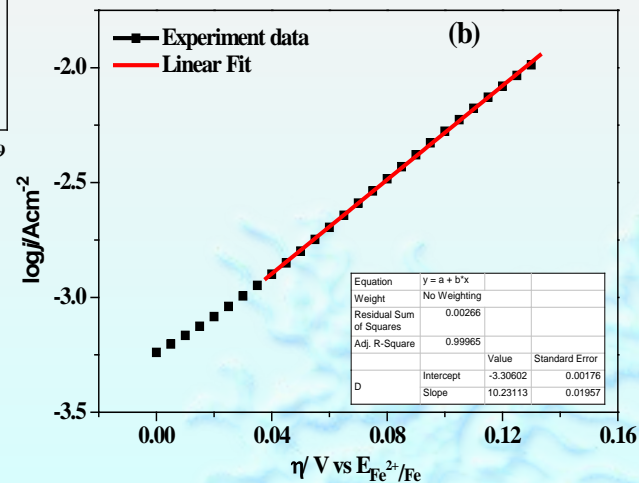
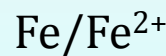
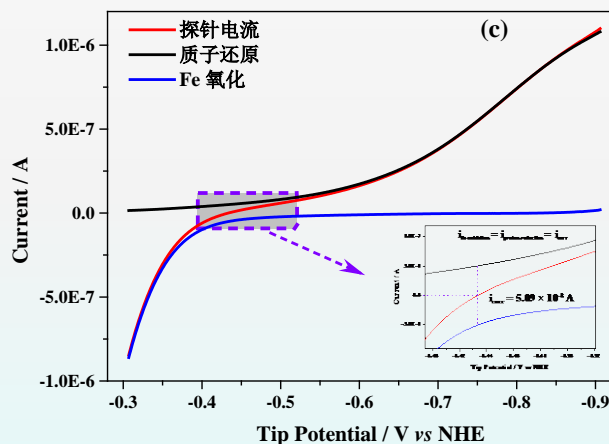
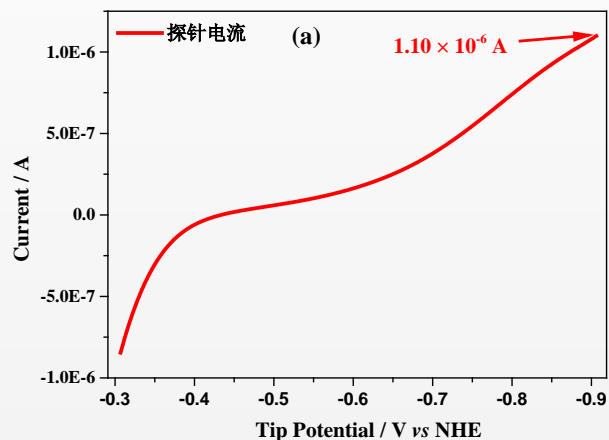


➤ 标准速率常数  $k^0 = 9.2 \times 10^{-6} \text{ cm/s}$ ;

➤ 传递系数  $\alpha_H = 0.27$

➤ 标准速率常数  $k^0 = 2.5 \times 10^{-6} \text{ cm/s}$ ;

➤ 传递系数  $\alpha_H = 0.7$



# 展望

- ◆ SECM强大，应用广泛。
- ◆ 数据定量化需要COMSOL的支持。

**谢谢大家，请批评指正！**

